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SPECIFICATION

PART NO.: MT5470B-OR

5.2×4.6mm OVAL LED LAMP

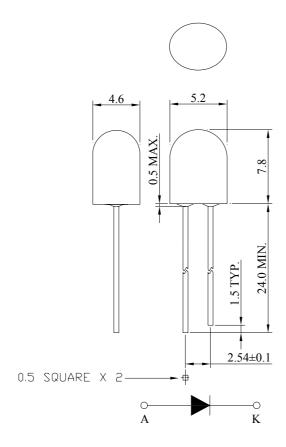






Description

This amber lamp is made with AlGaInP/GaAs chip and white diffused epoxy resin.



Notes:

- 1. All dimensions are in mm.
- 2. Tolerance is \pm 0.25mm unless otherwise noted.

Description

	LED Chip		
Part No.	Material	Emitting Color	Lens Color
MT5470B-OR	AlGaInP/GaAs	Amber	White diffused

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Absolute Maximum Ratings at Ta=25

Parameter	Symbol	Rating	Unit
Power Dissipation	PD	125	mW
Reverse Voltage	VR	5	V
D.C. Forward Current	If	50	mA
Reverse (Leakage) Current	Ir	100	μA
Peak Current(1/10Duty Cycle,0.1ms Pulse Width.)	If(Peak)	200	mA
Operating Temperature Range	Topr.	-40 to +95	
Storage Temperature Range	Tstg.	-40 to +100	
Soldering Temperature(1.6mm from body)	Tsol.	Dip Soldering : 260 for 5 Hand Soldering : 350 for 3	

Electrical and Optical Characteristics:

Parai	meter	Symbol	Condition	Min.	Тур.	Max.	Unit
Luminous Intens	ity	Iv	If=20mA	770	1100		mcd
Forward Voltage		Vf	If=20mA		1.9	2.5	V
Peak Wavelength	1	λр	If=20mA		610		nm
Dominant Wavel	ength	λd	If=20mA	600	605	609	nm
Reverse (Leakag	e) Current	Ir	Vr=5V			100	μΑ
ViewingAngle	VERTICAL	2 1/2	If=20mA		30		deg
	HORIZONTAL	2 1/2	If=20mA		60		
Spectrum Line H	alfwidth	Δλ	If=20mA		17		nm

Notes: 1. The datas tested by IS tester.

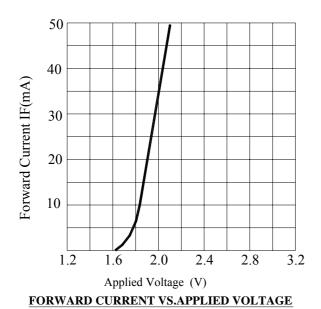
2. Customer's special requirements are also welcome.

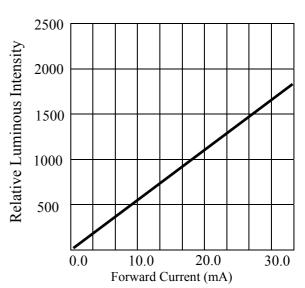
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Typical Electrical / Optical Characteristics Curves:



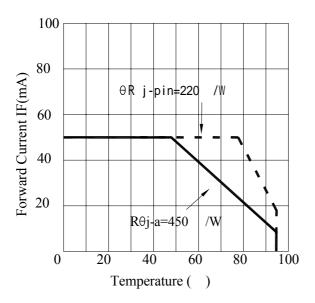


FORWARD CURRENT VS. LUMINOUS INTENSITY

0°

20°

10°



30° HORIZONTAL VERTICAL 40° 1.0 50° 0.9 60° 0.8 70° 80° 90° 0.7 0.5 0.3 0.2 0.4 0.6 0.1

FORWARD CURRENT VS. AMBIENT TEMPERATURE

RADIATION DIAGRAM

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Specifications for Bin Grading:

Iv(mcd)		
BIN	MIN.	MAX.
S	770	1100
T	1100	1520
U	1520	2130

Specifications for Vf Group:

Vf(V)		
Group	MIN.	MAX.
V1	1.6	1.8
V2	1.8	2.0
V3	2.0	2.2
V4	2.2	2.4
V5	2.4	2.6

^{*}Majority VF bins are highlighted in Yellow.

Specifications for Wavelength Group:

D(nm) @20mA			
Group	MIN.	MAX.	
X2	600	603	
X3	603	606	
X4	606	609	

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5.2×4.6mm OVAL LED LAMP

Precautions:

TAKE NOTE OF THE FOLLOWING IN USE OF LED

1. Temperature in use

Since the light generated inside the LED needs to be emitted to outside efficiently, a resin with high light transparency is used; therefore, additives to improve the heat resistance or moisture resistance (silica gel, etc) which are used for semiconductor products such as transistors cannot be added to the resin.

Consequently, the heat resistant ability of the resin used for LED is usually low; therefore, please be careful on the following during use.

Avoid applying external force, stress, and excessive vibration to the resins and terminals at high temperature. The glass transition temperature of epoxy resin used for the LED is approximately 120-130 .

At a temperature exceeding this limit, the coefficient of liner expansion of the resin doubles or more compared to that at normal temperature and the resin is softened.

If external force or stress is applied at that time, it may cause a wire rupture.

2. Soldering

Please be careful on the following at soldering.

After soldering, avoided applying external force, stress, and excessive vibration until the products go to cooling process (normal temperature), <Same for products with terminal leads>

(1) Soldering measurements:

Distance between melted solder side to bottom of resin shall be 1.6mm or longer.

(2) Dip soldering:

Pre-heat: 90 max. (Backside of PCB), Within 60 seconds.

Solder bath: 260±5 (Solder temperature), Within 5 seconds.

(3) Hand soldering: 350 max. (Temperature of soldering iron tip), Within 3 seconds.

3. Insertion

Pitch of the LED leads and pitch of mounting holes need to be same.

4. Others

Since the heat resistant ability of the LED resin is low, SMD components are used on the same PCB, please mount the LED after adhesive baking process for SMD components. In case adhesive baking is done after LED lamp insertion due to a production process reason, make sure not to apply external force, stress, and excessive vibration to the LED and follow the conditions below.

Baking temperature: 120 max. Baking time: Within 60 seconds.

If soldering is done sequentially after the adhesive baking, please perform the soldering after cooling down the LED to normal temperature.

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